![SGS-THOMSON MICROELECTRONICS logo]

M54HC221/221A
M74HC221/221A

DUAL MONOSTABLE MULTIVIBRATOR

- **HIGH SPEED**
  t_{PD} = 25 ns (TYP) at V_{CC} = 5V
- **LOW POWER DISSIPATION**
  STANDBY STATE I_{CC}=4 μA (MAX.) AT T_A=25°C
  ACTIVE STATE I_{CC} = 700 μA (MAX.) AT V_{CC}=5V
- **HIGH NOISE IMMUNITY**
  V_{NIH} = V_{NIL} = 28 % V_{CC} (MIN.)
- **OUTPUT DRIVE CAPABILITY**
  10 LSTTL LOADS
- **SYMMETRICAL OUTPUT IMPEDANCE**
  I_{OH} = I_{OL} = 4 mA (MIN.)
- **BALANCED PROPAGATION DELAYS**
  t_{PLH} = t_{PHL}
- **WIDE OPERATING VOLTAGE RANGE**
  V_{CC} (OPR) = 2 V TO 6 V
- **WIDE OUTPUT PULSE WIDTH RANGE**
  t_{WOUT} = 150 ns ~ 60 s OVER AT V_{CC} = 4.5 V
- **PIN AND FUNCTION COMPATIBLE WITH 54/74LS221**

DESCRIPTION

The M54/74HC221/221A are high speed CMOS MONOSTABLE multivibrators fabricated with silicon gate C^{2}MOS technology. It achieves the high speed operation similar to equivalent LSTTL while maintaining the CMOS low power dissipation. There are two trigger inputs, $\overline{A}$ INPUT (negative edge) and B INPUT (positive edge). Triggering on the B input occurs at a particular voltage threshold and is not related to the rise and fall time of the applied pulse.

The device may also be triggered by using the $\overline{CLR}$ input (positive-edge) because of the Schmitt-trigger input ; after triggering the output maintains the MONOSTABLE state for the time period determined by the external resistor Rx and capacitor Cx. Taking $\overline{CLR}$ low breaks this MONOSTABLE STATE. If the next trigger pulse occurs during the MONOSTABLE period it makes the MONOSTABLE period longer.
Limit for values of Cx and Rx :
Cx : NO LIMIT
Rx : V_{CC} < 3.0 V 5 K Ω to 1 M Ω
    V_{CC} ≥ 3.0 V 1 K Ω to 1 M Ω
Two different pulse width constants are available:
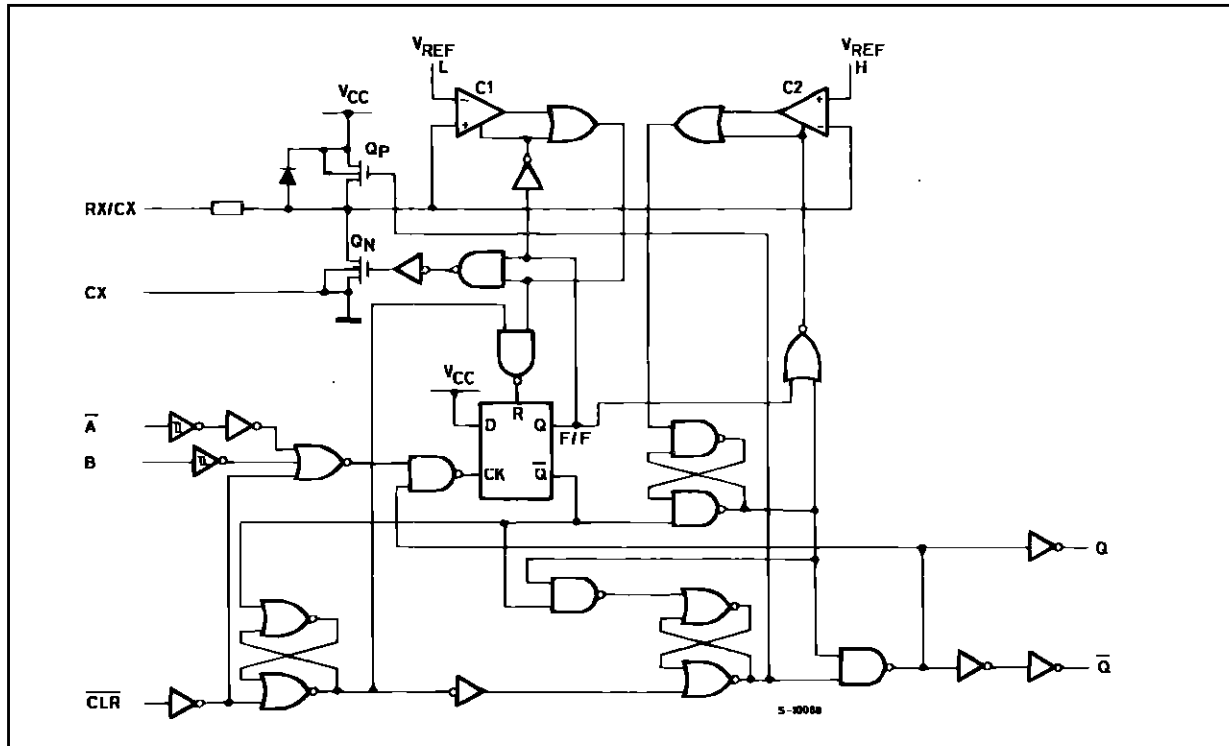K ≅ 0.7 for HC221
K ≅ 1 for HC221A
All inputs are equipped with protection circuits against static discharge and transient excess voltage.

B1R
(Plastic Package)

F1R
(Ceramic Package)

M1R
(Micro Package)

C1R
(Chip Carrier)

ORDER CODES :
M54HCXXXF1R   M74HCXXXXM1R
M74HCXXXB1R   M74HCXXXC1R

PIN CONNECTIONS (top view)

$\overline{1A}$	1	16	V_{CC}
1B	2	15	1 R/C EXT
$\overline{1CLR}$	3	14	1 C EXT
$\overline{1Q}$	4	13	1Q
2Q	5	12	$\overline{2Q}$
2 C EXT	6	11	$\overline{2 CLR}$
2 R/C EXT	7	10	2B
GND	8	9	$\overline{2A}$

S-7169

NC =
No Internal
Connection

S-7170
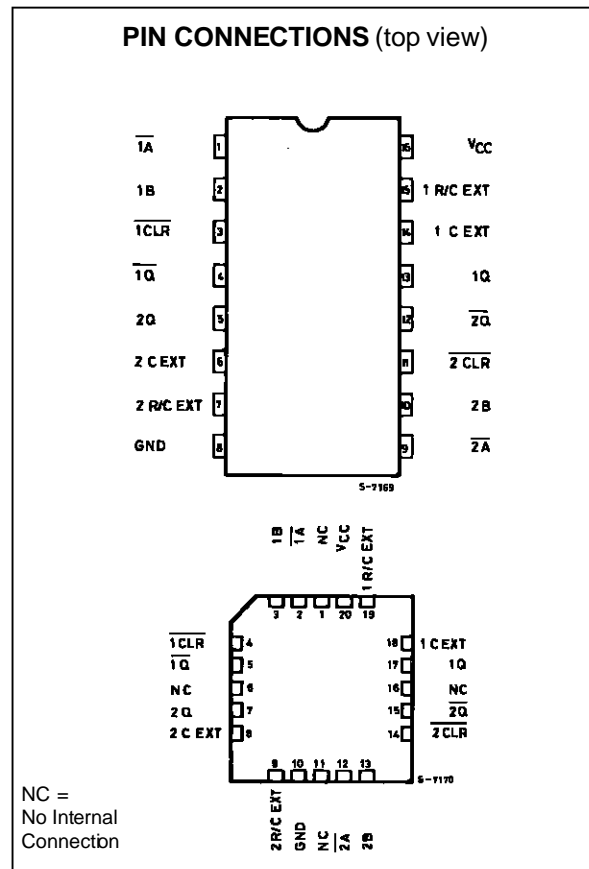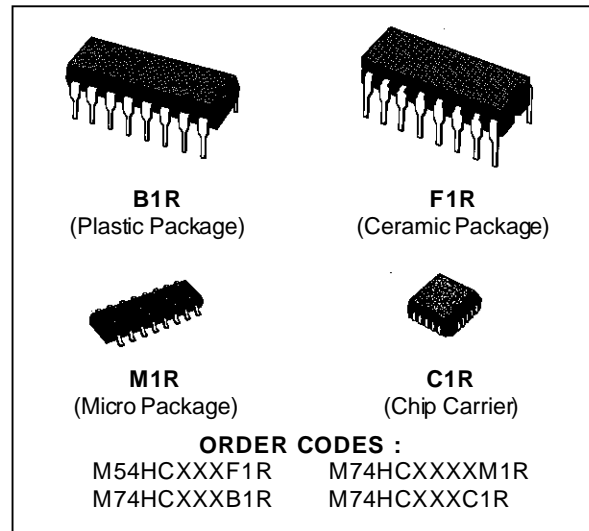
SYSTEM DIAGRAM

TIMING CHART

SGS-THOMSON
MICROELECTRONICS

BLOCK DIAGRAM

Note :

(1) Cx, Rx, Dx are external components.

(2) Dx is a clamping diode.

The external capacitor is charged to V_{CC} in the stand-by state, i.e. no trigger. When the supply voltage is turned off Cx is discharged mainly through an internal parasitic diode (see figures). If Cx is sufficiently large and V_{CC} decreases rapidy, there will be some possibility of damaging the I.C. with a surge current or latch-up. If the voltage supply filter capacitor is large enough and V_{CC} decrease slowly, the surge current is automatically limited and damage the I.C. is avoided. The maximum forward current of the parasitic diode is approximately 20 mA. In cases where Cx is large the time taken for the supply voltage to fall to 0.4 V_{CC} can be calculated as follows :

$t_f \geq (V_{CC} - 0.7) \cdot Cx/20mA$

In cases where t_f is too short an external clamping diode is required to protect the I.C. from the surge current.

FUNCTIONAL DESCRIPTION

STAND-BY STATE

The external capacitor, Cx, is fully charged to V_{CC} in the stand-by state. Hence, before triggering, transistor Qp and Qn (connected to the Rx/Cx node) are both turned-off. The two comparators that control the timing and the two reference voltage sources stop operating. The total supply current is therefore only leakage current.

TRIGGER OPERATION

Triggering occurs when :

1st) A is "low" and B has a falling edge ;
2nd) B is "high" and A has a rising edge ;
3rd) A is low and B is high and C1 has a rising edge.

After the multivibrator has been retriggered comparator C1 and C2 start operating and Qn is turned on. Cx then discharges through Qn. The voltage at the node R/C external falls.

When it reaches V_{REFL} the output of comparator C1 becomes low. This in turn resets the flip-flop and Qn is turned off.

At this point C1 stops functioning but C2 continues to operate.

The voltage at R/C external begins to rise with a time constant set by the external components Rx, Cx.

Triggering the multivibrator causes Q to go high after internal delay due to the flip-flop and the gate. Q remains high until the voltage at R/C external rises again to V_{REFH}. At this point C2 output goes low and O goes low. C2 stop operating. That means that after triggering when the voltage R/C external returns to V_{REFH} the multivibrator has returned to its MONOSTABLE STATE. In the case where Rx · Cx are large enough and the discharge time of the capacitor and the delay time in the I.C. can be ignored, the width of the output pulse tw (out) is as follows :

$$t_{W(OUT)} = 0.70 \, Cx \cdot Rx \quad (HC221)$$
$$t_{W(OUT)} = Cx \cdot Rx \quad (HC221A)$$

RESET OPERATION

CL is normally high. If CL is low, the trigger is not effective because Q output goes low and trigger control flip-flop is reset.

Also transistor Op is turned on and Cx is charged quicky to V_{CC}. This means if CL input goes low, the IC becomes waiting state both in operating and non operating state.
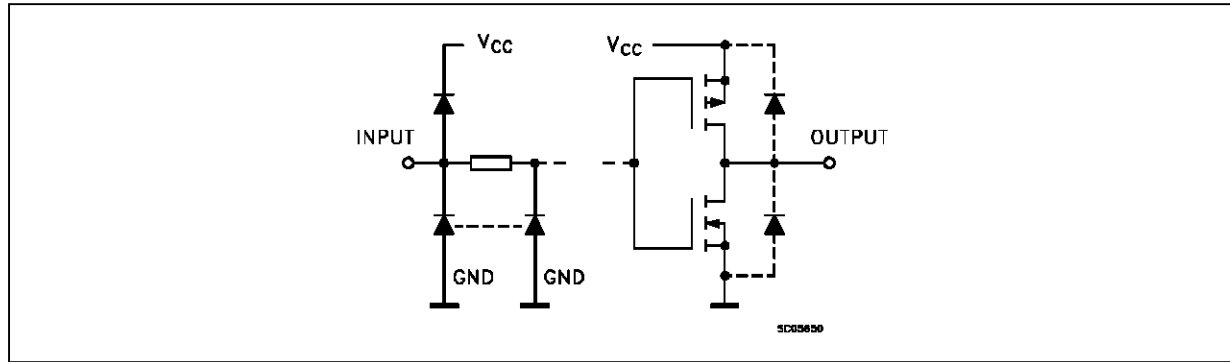
TRUTH TABLE

INPUTS			OUTPUTS		NOTE
A̅	B	CLR̅	Q	Q̅	
⎍	H	H	⎍⎍	⎍⎍	OUTPUT ENABLE
X	L	H	L (*)	H (*)	INHIBIT
H	X	H	L (*)	H (*)	INHIBIT
L	⎍	H	⎍⎍	⎍⎍	OUTPUT ENABLE
L	H	⎍	⎍⎍	⎍⎍	OUTPUT ENABLE
X	X	L	L	H	INHIBIT

X: Don't Care   (*): Except for monostble period

INPUT AND OUTPUT EQUIVALENT CIRCUIT

SC05650

PIN DESCRIPTION

PIN No	SYMBOL	NAME AND FUNCTION
1, 9	1A̅, 2A̅	Trigger Inputs (Negative Edge Triggered)
2, 10	1B, 2B	Trigger Inputs (Positive Edge Triggered)
3, 11	1CLR̅, 2CLR̅	Direct Reset LOW and Trigger Action at Positive Edge
4, 12	1Q̅, 2Q̅	Outputs (Active LOW)
7	2R$_{EXT}$/C$_{EXT}$	External Resistor Capacitor Connection
13, 5	1Q, 2Q	Outputs (Active HIGH)
14, 6	1C$_{EXT}$ 2C$_{EXT}$	External Capacitor Connection
15	1R$_{EXT}$/C$_{EXT}$	External Resistor Capacitor Connection
8	GND	Ground (0V)
16	V$_{CC}$	Positive Supply Voltage

IEC LOGIC SYMBOL

LC12960

SGS-THOMSON
MICROELECTRONICS
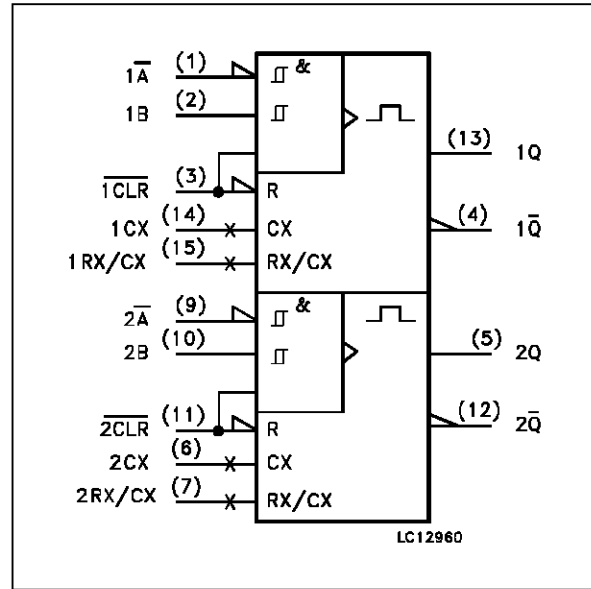
ABSOLUTE MAXIMUM RATING

Symbol	Parameter	Value	Unit
V_{CC}	Supply Voltage	-0.5 to +7	V
V_I	DC Input Voltage	-0.5 to V_{CC} + 0.5	V
V_O	DC Output Voltage	-0.5 to V_{CC} + 0.5	V
I_{IK}	DC Input Diode Current	$\pm$ 20	mA
I_{OK}	DC Output Diode Current	$\pm$ 20	mA
I_O	DC Output Source Sink Current Per Output Pin	$\pm$ 25	mA
I_{CC} or I_{GND}	DC V_{CC} or Ground Current	$\pm$ 50	mA
P_D	Power Dissipation	500 (*)	mW
T_{stg}	Storage Temperature	-65 to +150	^{o}C
T_L	Lead Temperature (10 sec)	300	^{o}C

Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these condition is not implied.
(*) 500 mW: $\cong$ 65 ^{o}C derate to 300 mW by 10mW/^{o}C: 65 ^{o}C to 85 ^{o}C

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter		Value	Unit
V_{CC}	Supply Voltage		2 to 6	V
V_I	Input Voltage		0 to V_{CC}	V
V_O	Output Voltage		0 to V_{CC}	V
T_{op}	Operating Temperature: **M54HC** Series		-55 to +125	^{o}C
	M74HC Series		-40 to +85	^{o}C
t_r, t_f	Input Rise and Fall Time ($\overline{CLR}$ and $\overline{A}$ only)	V_{CC} = 2 V	0 to 1000	ns
		V_{CC} = 4.5 V	0 to 500	
		V_{CC} = 6 V	0 to 400	
C_X	External Capacitor		> 100 (*)	pF
R_X	External Resistor	V_{CC} < 3 V	5K to 1M (*)	Ω
		$V_{CC} \geq$ 3 V	1K to 1M (*)	

(*)The maximum allowable values of Cx and Rx are a function of leackage of capacitor Cx, the leackage of HC221/A, and leackage due to the board layout and surface resistance. Susceptibility to externally induced noise signals may occur for Rx > 1MΩ

SGS-THOMSON
MICROELECTRONICS

DC SPECIFICATIONS

Symbol	Parameter	Test Conditions Vcc (V)			Value TA = 25 °C 54HC and 74HC			-40 to 85 °C 74HC		-55 to 125 °C 54HC		Unit
					Min.	Typ.	Max.	Min.	Max.	Min.	Max.	
V_{IH}	High Level Input Voltage	2.0			1.5			1.5		1.5		V
		4.5			3.15			3.15		3.15		
		6.0			4.2			4.2		4.2		
V_{IL}	Low Level Input Voltage	2.0					0.5		0.5		0.5	V
		4.5					1.35		1.35		1.35	
		6.0					1.8		1.8		1.8	
V_{OH}	High Level Output Voltage (Q, $\overline{Q}$ Output)	2.0	$V_I = V_{IH}$ or V_{IL}	I_O=-20 µA	1.9	2.0		1.9		1.9		V
		4.5			4.4	4.5		4.4		4.4		
		6.0			5.9	6.0		5.9		5.9		
		4.5		I_O=-4.0 mA	4.18	4.31		4.13		4.10		
		6.0		I_O=-5.2 mA	5.68	5.8		5.63		5.60		
V_{OL}	Low Level Output Voltage (Q, $\overline{Q}$ Output)	2.0	$V_I = V_{IH}$ or V_{IL}	I_O= 20 µA		0.0	0.1		0.1		0.1	V
		4.5				0.0	0.1		0.1		0.1	
		6.0				0.0	0.1		0.1		0.1	
		4.5		I_O= 4.0 mA		0.17	0.26		0.33		0.40	
		6.0		I_O= 5.2 mA		0.18	0.26		0.33		0.40	
I_I	Input Leakage Current	6.0	$V_I = V_{CC}$ or GND				±0.1		±1		±1	µA
I_I	R/C Terminal Off State Current	6.0	$V_I = V_{CC}$ or GND				±0.5		±5		±10	µA
I_{CC}	Quiescent Supply Current	6.0	$V_I = V_{CC}$ or GND				4		40		80	µA
I_{CC}'	Active State Supply Current (1)	2.0	$V_I = V_{CC}$ or GND $V_{IN} = V_{CC}/2$			45	250		260		350	µA
		4.5				400	530		650		850	µA
		6.0				0.7	1		1.3		1.7	mA

(1): Per Circuit

SGS-THOMSON
MICROELECTRONICS

AC ELECTRICAL CHARACTERISTICS (C_L = 50 pF, Input t_r = t_f = 6 ns)

| Symbol	Parameter	Test Conditions		Value							Unit
		V_{CC} (V)		T_A = 25 °C 54HC and 74HC			-40 to 85 °C 74HC		-55 to 125 °C 54HC		
				Min.	Typ.	Max.	Min.	Max.	Min.	Max.	
t_{TLH} t_{THL}	Output Transition Time	2.0			30	75		95		110	ns
		4.5			8	15		19		22	
		6.0			7	13		16		19	
t_{PLH} t_{PHL}	Propagation Delay Time ($\overline{A}$, B - Q, $\overline{Q}$)	2.0			102	210		265		315	ns
		4.5			30	42		53		63	
		6.0			24	36		45		54	
t_{PLH} t_{PHL}	Propagation Delay Time ($\overline{CLR\ TRIGGER}$ - Q, $\overline{Q}$)	2.0			102	235		295		355	ns
		4.5			30	47		59		71	
		6.0			24	40		50		60	
t_{PLH} t_{PHL}	Propagation Delay Time ($\overline{CLR}$ - Q, $\overline{Q}$)	2.0			67	160		200		240	ns
		4.5			20	32		40		48	
		6.0			16	27		34		41	
t_{WOUT}	Output Pulse Width (for HC221)	2.0	C_X = 100 pF R_X = 10 KΩ		1.5						µs
		4.5			1.3						
		6.0			1.2						
		2.0	C_X = 0.1 µF R_X = 100 KΩ		7						ms
		4.5			6.9						
		6.0			6.9						
t_{WOUT}	Output Pulse Width (for HC221A)	2.0	C_X = 100 pF R_X = 10 KΩ		1.8						µs
		4.5			1.5						
		6.0			1.4						
		2.0	C_X = 0.1 µF R_X = 100 KΩ		10						ms
		4.5			9.7						
		6.0			9.6						
Δt_{WOUT}	Output Pulse Width Error Between Circuits in Same Package				±1						%
$t_{W(H)}$ $t_{W(L)}$	Minimum Pulse Width	2.0				75		95		110	ns
		4.5				15		19		22	
		6.0				13		16		20	
$t_{W(L)}$	Minimum Pulse Width	2.0				75		95		110	ns
		4.5				15		19		22	
		6.0				13		16		20	
C_{IN}	Input Capacitance				5	10		10		10	pF
C_{PD} (*)	Power Dissipation Capacitance				174						pF

(*) C_{PD} is defined as the value of the IC's internal equivalent capacitance which is calculated from the operating current consumption without load. (Refer to Test Circuit). Average operting current can be obtained by the following equation. $I_{CC}(opr) = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}'$ Duty/100 + I_C/2 (per monostable) (I_{CC}': Active Supply Current) (Duty:%)
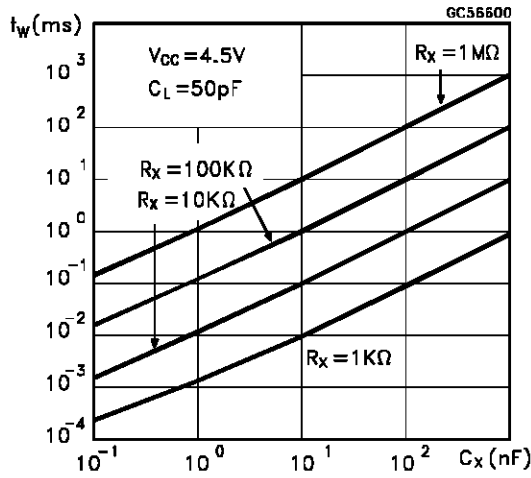
SGS-THOMSON MICROELECTRONICS

Output Pulse Width Constant Characteristics
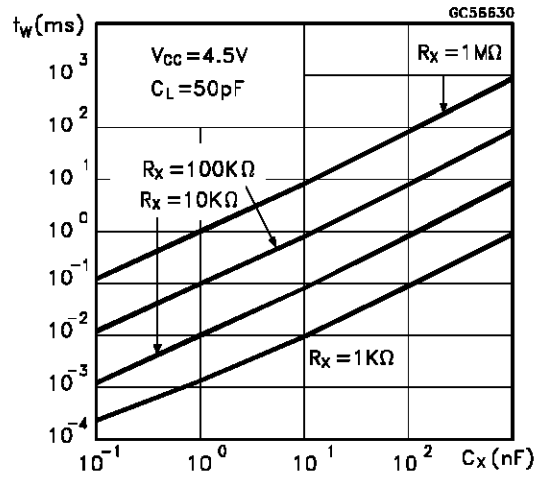(for HC221)
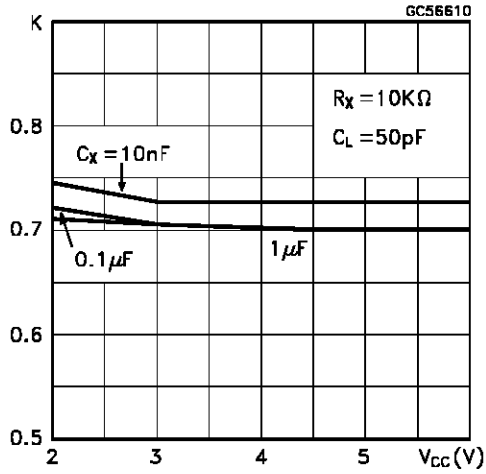
Output Pulse Width Constant Characteristics
(for HC221A)

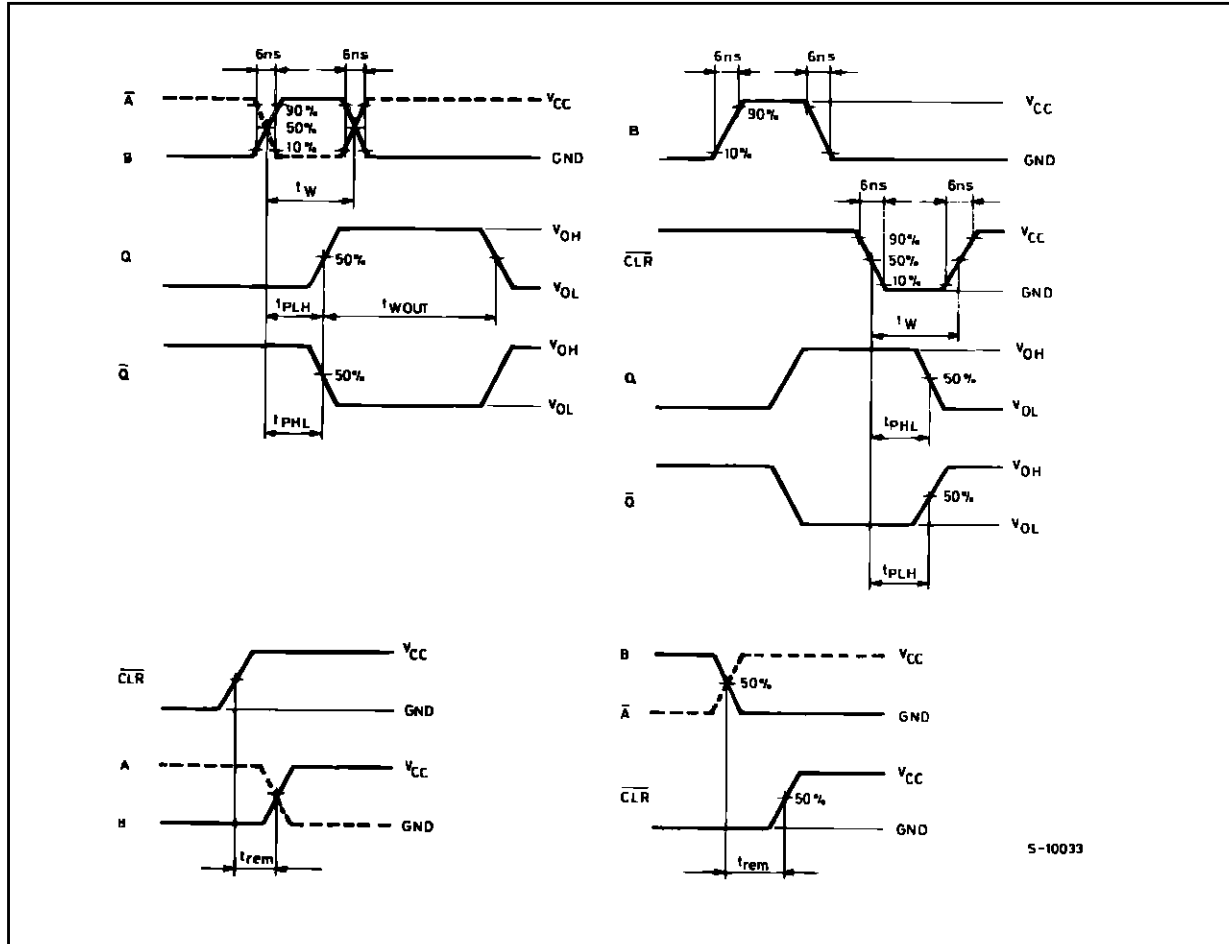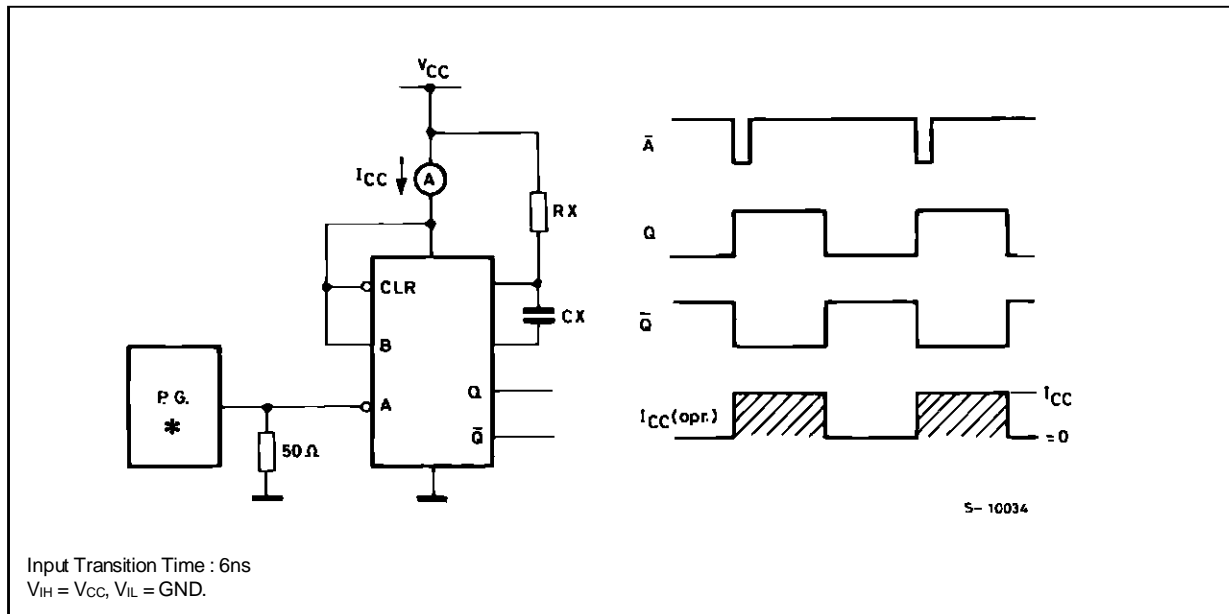Output Pulse Width Characteristics (for HC221)

Output Pulse Width Characteristics (for HC221A)

SGS-THOMSON
MICROELECTRONICS
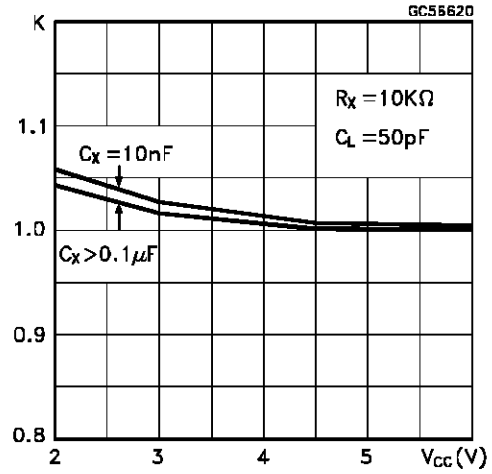
SWITCHING CHARACTERISTICS TEST WAVEFORM

TEST WAVEFORM

Input Transition Time : 6ns
$V_{IH} = V_{CC}$, $V_{IL} = GND$.

SGS-THOMSON
MICROELECTRONICS

Plastic DIP16 (0.25) MECHANICAL DATA

DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
a1	0.51			0.020		
B	0.77		1.65	0.030		0.065
b		0.5			0.020	
b1		0.25			0.010	
D			20			0.787
E		8.5			0.335	
e		2.54			0.100	
e3		17.78			0.700	
F			7.1			0.280
I			5.1			0.201
L		3.3			0.130	
Z			1.27			0.050

P001C

Ceramic DIP16/1 MECHANICAL DATA

DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A			20			0.787
B			7			0.276
D		3.3			0.130	
E	0.38			0.015		
e3		17.78			0.700	
F	2.29		2.79	0.090		0.110
G	0.4		0.55	0.016		0.022
H	1.17		1.52	0.046		0.060
L	0.22		0.31	0.009		0.012
M	0.51		1.27	0.020		0.050
N			10.3			0.406
P	7.8		8.05	0.307		0.317
Q			5.08			0.200

P053D

SGS-THOMSON
MICROELECTRONICS

SO16 (Narrow) MECHANICAL DATA

DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A			1.75			0.068
a1	0.1		0.2	0.004		0.007
a2			1.65			0.064
b	0.35		0.46	0.013		0.018
b1	0.19		0.25	0.007		0.010
C		0.5			0.019	
c1	45° (typ.)					
D	9.8		10	0.385		0.393
E	5.8		6.2	0.228		0.244
e		1.27			0.050	
e3		8.89			0.350	
F	3.8		4.0	0.149		0.157
G	4.6		5.3	0.181		0.208
L	0.5		1.27	0.019		0.050
M			0.62			0.024
S	8° (max.)					

P013H

SGS-THOMSON
MICROELECTRONICS

PLCC20 MECHANICAL DATA

DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A	9.78		10.03	0.385		0.395
B	8.89		9.04	0.350		0.356
D	4.2		4.57	0.165		0.180
d1		2.54			0.100	
d2		0.56			0.022	
E	7.37		8.38	0.290		0.330
e		1.27			0.050	
e3		5.08			0.200	
F		0.38			0.015	
G			0.101			0.004
M		1.27			0.050	
M1		1.14			0.045	

P027A

SGS-THOMSON
MICROELECTRONICS

SGS-THOMSON Microelectronics GROUP OF COMPANIES
Australia - Brazil - France - Germany - Hong Kong - Italy - Japan - Korea - Malaysia - Malta - Morocco - The Netherlands -
Singapore - Spain - Sweden - Switzerland - Taiwan - Thailand - United Kingdom - U.S.A

SGS-THOMSON
MICROELECTRONICS